## **Lawrence Berkeley National Laboratory**

### **Advanced Light Source**

#### Title

Two-dimensional Ferromagnetic Superlattices

#### **Permalink**

https://escholarship.org/uc/item/0839282m

#### **Journal**

National Science Review, 7(4)

#### **ISSN**

2095-5138

#### **Authors**

Liu, Shanshan Yang, Ke Liu, Wenqing et al.

#### **Publication Date**

2020-04-01

#### DOI

10.1093/nsr/nwz205

## **Copyright Information**

This work is made available under the terms of a Creative Commons Attribution License, available at https://creativecommons.org/licenses/by/4.0/

Peer reviewed

# RESEARCH ARTICLE

National Science Review 7: 745–754, 2020 doi: 10.1093/nsr/nwz205 Advance access publication 16 December 2019

<sup>1</sup>State Key Laboratory of Surface Physics and Department of Physics. Fudan University Shanghai 200433 China; <sup>2</sup>Institute for Nanoelectronic Devices and Quantum Computing, Fudan University, Shanghai 200433. China: <sup>3</sup>I aboratory for Computational Physical Sciences (MOE), Fudan University, Shanghai 200433, China; Denartment of Electronic Engineering, Roval Holloway University of London. Egham TW20 0EX, UK; <sup>5</sup>School of Electronic Science and Engineering, Nanjing University, Nanjing 210093, China; <sup>6</sup>Materials Engineering, The University of Queensland, Brisbane QLD 4072, Australia; <sup>7</sup>Department of Physics, National University of Singapore, Singapore 117542, Singapore; <sup>8</sup>Centre for Advanced 2D Materials and Graphene Research Centre, National University of Singapore, Singapore 117546, Singapore; <sup>9</sup>Lawrence Berkelev National Laboratory, Berkeley, CA 94720, USA; 10 School of Information Science and Technology, ShanghaiTech University, Shanghai 201210, China; <sup>1</sup>Centre for Microscopy and Microanalysis, The University of Queensland, Brisbane QLD 4072, Australia and <sup>12</sup>Collaborative Innovation Center of Advanced Microstructures Nanjing 210093, China

\*Corresponding authors. E-mails: Faxian@fudan.edu.cn; wuh@fudan.edu.cn †Equally contributed to this work.

Received 2 October 2019; Revised 2 December 2019; Accepted 13 December 2019

#### MATERIALS SCIENCE

## Two-dimensional ferromagnetic superlattices

Shanshan Liu<sup>1,2,†</sup>, Ke Yang<sup>1,3,†</sup>, Wenqing Liu<sup>4,†</sup>, Enze Zhang<sup>1,2</sup>, Zihan Li<sup>1,2</sup>, Xiaoqian Zhang<sup>5</sup>, Zhiming Liao<sup>6</sup>, Wen Zhang<sup>7</sup>, Jiabao Sun<sup>4</sup>, Yunkun Yang<sup>1,2</sup>, Han Gao<sup>6</sup>, Ce Huang<sup>1,2</sup>, Linfeng Ai<sup>1,2</sup>, Ping Kwan Johnny Wong<sup>8</sup>, Andrew Thye Shen Wee<sup>7,8</sup>, Alpha T. N'Diaye<sup>9</sup>, Simon A. Morton<sup>9</sup>, Xufeng Kou<sup>10</sup>, Jin Zou<sup>6,11</sup>, Yongbing Xu<sup>5</sup>, Hua Wu<sup>1,3,12,\*</sup> and Faxian Xiu <sup>1,2,12,\*</sup>

#### **ABSTRACT**

Mechanically exfoliated two-dimensional ferromagnetic materials (2D FMs) possess long-range ferromagnetic order and topologically nontrivial skyrmions in few layers. However, because of the dimensionality effect, such few-layer systems usually exhibit much lower Curie temperature  $(T_{\rm C})$  compared to their bulk counterparts. It is therefore of great interest to explore effective approaches to enhance their  $T_{\rm C}$ , particularly in wafer-scale for practical applications. Here, we report an interfacial proximity-induced high-T<sub>C</sub> 2D FM Fe<sub>3</sub>GeTe<sub>2</sub> (FGT) via A-type antiferromagnetic material CrSb (CS) which strongly couples to FGT. A superlattice structure of  $(FGT/CS)_n$ , where n stands for the period of FGT/CS heterostructure, has been successfully produced with sharp interfaces by molecular-beam epitaxy on 2-inch wafers. By performing elemental specific X-ray magnetic circular dichroism (XMCD) measurements, we have unequivocally discovered that T<sub>C</sub> of 4-layer Fe<sub>3</sub>GeTe<sub>2</sub> can be significantly enhanced from 140 K to 230 K because of the interfacial ferromagnetic coupling. Meanwhile, an inverse proximity effect occurs in the FGT/CS interface, driving the interfacial antiferromagnetic CrSb into a ferrimagnetic state as evidenced by double-switching behavior in hysteresis loops and the XMCD spectra. Density functional theory calculations show that the Fe-Te/Cr-Sb interface is strongly FM coupled and doping of the spin-polarized electrons by the interfacial Cr layer gives rise to the  $T_{\rm C}$  enhancement of the Fe<sub>3</sub>GeTe<sub>2</sub> films, in accordance with our XMCD measurements. Strikingly, by introducing rich Fe in a 4-layer FGT/CS superlattice,  $T_{\rm C}$  can be further enhanced to near room temperature. Our results provide a feasible approach for enhancing the magnetic order of few-layer 2D FMs in wafer-scale and render opportunities for realizing realistic ultra-thin spintronic devices.

**Keywords:** 2D ferromagnetic material, room temperature, 2-inch  $Fe_3GeTe_2$  film wafers, proximity effect,  $(Fe_3GeTe_2/CrSb)_n$  superlattice

#### INTRODUCTION

Two-dimensional (2D) systems involving various functionalities are a central topic in condensed matter physics. Since the discovery of graphene [1,2], the 2D material family has been widely explored in semiconductors [3,4], superconductors [5,6], and ferromagnetic materials (FMs) [7–12]. In particular, spintronic devices based on 2D FMs have attracted significant attention, for example, magnon-assisted tunneling and giant tunneling magnetoresistances were found to possess multiple magnetic

states in  $CrX_3$  (X = Br and I)-based junctions [13–17]. In 2D FMs, the perpendicular magnetic anisotropy that is partially contributed by spin-orbit coupling plays a more essential role in magnetic order as the thickness reduces [8,11]. Theoretically, because of strong spin-orbit coupling and broken inversion symmetry, Dzyaloshinskii-Moriya interactions [18,19] can provide topological magnetic textures, thus inducing skyrmions. Using Lorentz transmission electron microscopy (TEM), at low temperatures Néel-type skyrmions (magnetic

bubbles) have been observed in Fe<sub>3</sub>GeTe<sub>2</sub> (Cr<sub>2</sub>Ge<sub>2</sub>Te<sub>6</sub>) with controllable transitions between skyrmions and magnetic domains [20,21]. However, one unprecedented challenge still exists, that is the suppressed Curie temperature ( $T_{\rm C}$ ) as the thickness of 2D FMs decreases [7,11]; this is ascribed to the dimensionality effect of the competing perpendicular magnetic anisotropy energy with thermal fluctuations [11,22]. Modulation of the ferromagnetic properties in few-layer 2D FMs, such as enhancing  $T_{\rm C}$  or the control of the coercive field ( $H_{\rm C}$ ), provides a route towards realistic spintronic applications using 2D FMs.

Recent studies have unveiled the gate-controlled ferromagnetic order in 2D FM nanoflakes. As an example, the ferromagnetic parameters of  $T_{\rm C}$  and  $H_C$  for monolayer CrI<sub>3</sub> can be tuned via h-BN gating [23,24], and bilayer CrI<sub>3</sub> exhibits a reversible transition between antiferromagnetic (AF) and FM states [25]. Compared to other 2D FMs, Fe<sub>3</sub>GeTe<sub>2</sub> is more stable among the recently explored 2D FMs; and by changing the Fe composition [9,26] and applying ionic-liquid gating [11], the ferromagnetism of Fe<sub>3</sub>GeTe<sub>2</sub> can be modulated. Complementary to these doping and gating techniques, the proximity effect can induce a stable ferromagnetic order through interface coupling [27,28] and avoid the inconvenience of using dielectric gates for the transient FM states. For example, in Bi<sub>2</sub>Se<sub>3</sub>/EuS heterostructures, Bi<sub>2</sub>Se<sub>3</sub> possesses room-temperature ferromagnetism which is far above the intrinsic  $T_C$ of EuS (17 K) as a result of large spin-orbit coupling [29]; the quantum anomalous Hall effect in graphene has been proposed by proximity coupling to an antiferromagnetic insulator [30]. Except for the FM-induced interfacial magnetism [29,31,32], recent experimental observations suggest that the interplay between antiferromagnetic CrSb and ferromagnetic topological insulators can dramatically enhance the magnetic order in topological insulators with the interfacial spin texture modulation [33]. Such a practicable proximity effect potentially could be applied to control the ferromagnetism of 2D FMs.

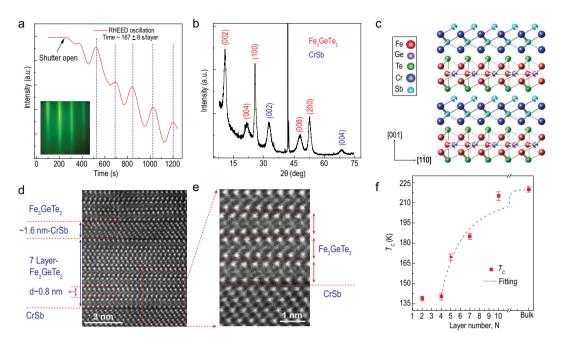
Here, we report control of the ferromagnetic order in 2D wafer-scale  $Fe_3GeTe_2$  films via the proximity effect using a molecular-beam epitaxy (MBE) growth technique. It is found that the  $T_C$  of  $Fe_3GeTe_2$  films reduces with decreasing the thickness, i.e. 220 K for the bulk, 140.3 K for 4-layer and 138.4 K for 2-layer  $Fe_3GeTe_2$ . By producing FM/AF-structured  $(FGT/CS)_n$  superlattices with clean interfaces, we find that the  $T_C$  of the 4-layer  $Fe_3GeTe_2$  can be monotonously enhanced from 140.3 K (n=0), to 206.3 (n=3) and finally to 230.9 K (n=10), driven by long-range interfacial exchange coupling. Simultaneously, the proximity

effect induces a double-switching behavior that gradually smears out as the temperature increases beyond 55 K. By performing temperaturedependent X-ray magnetic circular dichroism (XMCD), we prove that the enhanced  $T_{\rm C}$  originates from the superlattice Fe<sub>3</sub>GeTe<sub>2</sub> regions and the double-switching phenomenon stems from the interfacial ferrimagnetic CrSb. In line with these experimental findings, our density functional theory (DFT) calculations demonstrate that the doping of the spin-polarized electrons by the interfacial magnetic Cr layer favors the  $T_{\rm C}$  enhancement of the Fe<sub>3</sub>GeTe<sub>2</sub> films rather than the interfacial strain effect, and that the interfacial Cr layers retain the interlayer AF coupling but have a net magnetic moment. Furthermore, by designing 4-layer Fe-rich  $Fe_{3+x}GeTe_2$  and  $\sim 1.6$  nm CrSb with the same superlattice structure, we have accomplished the highest  $T_{\rm C}$  of 286.7 K in  $(Fe_{3+x}GeTe_2/CrSb)_3$ superlattice, which approaches room temperature with a stable ferromagnetic order over 12 months.

#### RESULTS AND DISCUSSION

Layer structured Fe<sub>3</sub>GeTe<sub>2</sub> has a hexagonal structure with a space group P63/mmc and lattice constants of a = b = 3.991 Å and c = 16.396 Å[34], in which each layer consists of five sublayers with Fe<sub>3</sub>Ge slab sandwiched between two Te layers [9,34]; and the A-type antiferromagnetic (A-AF) CrSb [35] is a NiAs-type structure with a space group of P6<sub>3</sub>/mmc and lattice constants of a = b = 4.108 Å and c = 5.440 Å [36], which serves as an ideal candidate for the epitaxial growth of FM/AF heterostructures. Periodic reflection high-energy electron diffraction (RHEED) intensity oscillations of Fe<sub>3</sub>GeTe<sub>2</sub> suggest a layer-by-layer growth mode as shown in Fig. 1a. It typically takes 167±8 s to complete 1-layer Fe<sub>3</sub>GeTe<sub>2</sub> growth, guaranteeing the fine controllability of the film thickness. Detailed growth conditions and high-crystalline characterizations are discussed in detail in the Method section and Supplementary Figs 1-2. Figure 1b displays a typical X-ray diffraction (XRD) spectrum for a (FGT/CS)<sub>6</sub> superlattice, in which all diffraction peaks can be exclusively indexed as Fe<sub>3</sub>GeTe<sub>2</sub> and CrSb without any mixtures or new compounds generated, with a schematic geometry of FGT/CS (Fig. 1c). The interlayer distance of Fe<sub>3</sub>GeTe<sub>2</sub> is half of *c*axis of  $\sim$ 0.8 nm (Fig. 1d), consistent with the (002) diffraction peak shown in Fig. 1b and the refinement-XRD value of 8.17 Å [34]. Sharp interfaces between Fe<sub>3</sub>GeTe<sub>2</sub> and CrSb are shown in the highangle-annular-dark-field (HAADF) image (Fig. 1d) with the enlarged part displayed in Fig. 1e, further excluding the possibility of element mixing at these interfaces or nearby layers.

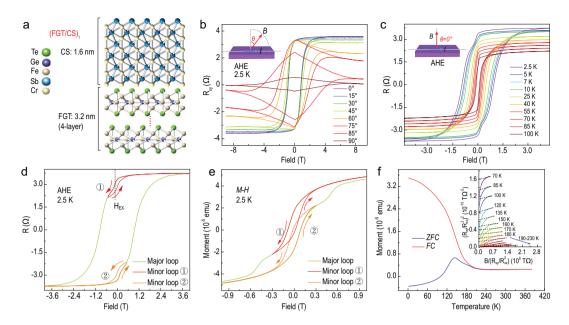
RESEARCH ARTICLE Liu et al. | 747



**Figure 1.** Thin-film growth and characterizations. (a) RHEED oscillations of 2D ferromagnetic  $Fe_3GeTe_2$  films. The layer-by-layer epitaxial mode can be verified by the periodic RHEED intensity oscillations, from which the growth period is determined to be  $\sim$ 167  $\pm$ 8 s per layer. The left inset is a streaky RHEED pattern, suggesting the smooth surface of  $Fe_3GeTe_2$ . (b) An XRD spectrum of  $(FGT/CS)_6$  superlattice. Peaks from  $Fe_3GeTe_2$  and CrSb are marked in red and blue, respectively. The epitaxial orientations of  $Fe_3GeTe_2$  and CrSb are ascribed to be along  $\langle 002 \rangle$  and  $\langle 002 \rangle$ , respectively. (c) A schematic geometry of FGT/CS superlattice. Ideally, the c-axis of  $Fe_3GeTe_2$  and CrSb should be along the same direction; however, experimentally, it has a slight deviation. (d) A cross-section HAADF image of a  $(FGT/CS)_3$  superlattice, where the thickness of CrSb is estimated to be  $\sim$ 1.6 nm and  $Fe_3GeTe_2$  is 7 layers ( $\sim$ 5.6 nm). (e) A zoom-in HAADF picture. Sharp interfaces between  $Fe_3GeTe_2$  and CrSb layers can be clearly distinguished. Note that the Pt layer is deposited during the TEM sample preparation process. (f) Thickness-dependent  $T_C$ . As the films become thinner,  $T_C$  has a dramatic drop from 220 K (bulk) to 138.4 K (bilayer) as a result of a strong dimensionality effect. The dashed line is a theoretical fit to the finite-size scaling law.

We then examined the thickness-dependent magnetic properties of Fe<sub>3</sub>GeTe<sub>2</sub> films by an anomalous Hall effect (AHE) in the Hall-bar geometry with a size of  $1.5 \times 2 \text{ mm}^2$ . Even down to 4 layers, the easy axis of Fe<sub>3</sub>GeTe<sub>2</sub> is still along the c-axis (out-of-plane) as  $H_C$  increases with the angle switching from 0° to 90° (see details in Supplementary Fig. 3a). As displayed in Fig. 1f, the Curie temperature (see details about Arrott-plots in Supplementary section 1) shows bulk-like behavior with  $T_{\rm C}$  of  $\sim$ 216.4 K when the thickness is above 8 nm ( $\sim$ 10 layers). However, when reducing the thickness,  $T_{\rm C}$  displays a declined trend and exhibits a dramatic drop below 7-layers. Further reducing to the bilayer, Fe<sub>3</sub>GeTe<sub>2</sub> retains a ferromagnetic state with  $T_C$  of 138.4  $\pm$  1.6 K. As the Fe<sub>3</sub>GeTe<sub>2</sub> thickness approaches the 2D limit, the thickness-dependent  $T_{\rm C}(N)$  can be described by a universal scaling law [37–39] written as  $(T_C(\infty) - T_C(N))/T_C(\infty) =$  $((N_0+1)/2N)^{\lambda}$ , where  $T_{\rm C}(\infty)$  denotes the  $T_{\rm C}$ of the bulk crystal, the critical exponent  $\lambda$  reveals the universality class of the transition, and  $N_0$  is the critical layer number referring to the mean spin-spin interaction range and separating the boundary between the 2D and 3D magnetism. The scaling law function is fitted to the experimental data yielding  $N_0 \sim 3.52 \pm 0.72$  and  $\lambda \sim 1.79 \pm 0.38$ . The deduced  $\lambda$  also suggests that Fe<sub>3</sub>GeTe<sub>2</sub> belongs to the Ising-type ferromagnet (note that  $\lambda = 1.42$  is from the Heisenberg model [40],  $\lambda = 1.56$  from the Ising model [41], and  $\lambda = 1$  from mean-field theory [38]). A crossover from 3D to 2D Ising ferromagnetism with the thickness decreasing has been reported in Fe<sub>3</sub>GeTe<sub>2</sub> nanoflakes [10]. The strong dimensionality effect can be commonly explained by the competition between the magnetic anisotropy energy and prominent thermal fluctuations in thinner samples [7,22].

To enhance the Curie temperature of Fe<sub>3</sub>GeTe<sub>2</sub>, we geometrically designed FGT/CS superlattices with different periods and thickness. Detailed characterizations of A-AF CrSb under in-plane and out-of-plane magnetic fields are presented in Supplementary Fig. 4, with no sign of ferromagnetism in both measurement geometries. Here, we denote Fe<sub>3</sub>GeTe<sub>2</sub>/CrSb superlattices to be (FGT/CS)<sub>n</sub>, where n is the period. Unless specifically mentioned, hereafter, the thickness of Fe<sub>3</sub>GeTe<sub>2</sub> and CrSb is  $\sim$ 3.2 nm (4-layer) and  $\sim$ 1.6 nm, respectively. n = 1 stands for the single-period structure

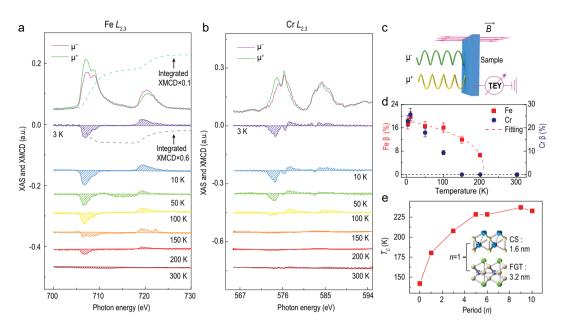


**Figure 2.** FM/AF interaction induced double-switching behavior in AHE/M-H curves and the enhanced  $T_{\rm C}$  in the (FGT/CS)<sub>3</sub> superlattice. (a) A schematic structure of one period FGT/CS superlattice that is made up of  $\sim$ 3.2 nm Fe<sub>3</sub>GeTe<sub>2</sub> (4-layer) and  $\sim$ 1.6 nm CrSb. (b) Angle-dependent AHE at 2.5 K with the measurement geometry defined in the inset. The easy axis is determined to be out-of-plane, the same as that of pure Fe<sub>3</sub>GeTe<sub>2</sub>. (c) Temperature-dependent AHE under perpendicular geometry. Inset shows the experimental setup. At 2.5 K, another small switching behavior appears at  $\sim$ ±0.18 T besides the sharp resistance jump at  $\sim$ ±0.96 T. Small hysteresis exists when scanning the magnetic field back and forth in a small field region, denoted as minor loops, as displayed in (d). The interaction between Fe<sub>3</sub>GeTe<sub>2</sub> and CrSb interface is manifested to be ferromagnetic coupling, evidenced by the negative exchange field  $H_{\rm EX}$  in minor loop $\odot$ . (e) Major and minor M-H loops at 2.5 K. (f) ZFC-FC data under 200 Oe for (FGT/CS)<sub>3</sub> superlattice.  $T_{\rm C}$  is roughly determined to be  $\sim$ 201 K, comparable to 206.3  $\pm$  1.6 K as deduced by the Arrott-plots in the inset.

of ~3.2 nm Fe<sub>3</sub>GeTe<sub>2</sub> and ~1.6 nm CrSb, as schematically shown in Fig. 2a. To confirm the magnetic anisotropy of (FGT/CS)<sub>3</sub> superlattice, angle-dependent AHE was performed (Fig. 2b). The easy axis of  $(FGT/CS)_3$  is still along the outof-plane direction, sharing the same perpendicular magnetic anisotropy as the pure Fe<sub>3</sub>GeTe<sub>2</sub>. Here, the temperature-dependent AHE was measured under perpendicular geometry (Fig. 2c inset). At low temperatures such as 2.5 K (Fig. 2c), the AHE presents a resistance switching at  $\pm 0.97$  T accompanied by another weaker switching behavior at a relatively low field. The origin of such property most likely comes from the FM/AF interface [33,42–44] and we define this phenomenon as double-switching behavior. With the temperature increasing, this behavior becomes inconspicuous at ~55 K, indicating decrease of the interface coupling. Figure 2d presents the switching behavior of the minor loops at low fields. Here, the exchange field  $(H_{\rm EX})$  is designated to describe the double-switching behavior. Negative  $H_{EX}$  in minor loop  $\bigcirc$  indicates that it is a parallel ferromagnetic coupling between the interfacial Fe<sub>3</sub>GeTe<sub>2</sub> and CrSb [42]. This doubleswitching property can also be observed at lowtemperature magnetization hysteresis (M-H curves, Fig. 2e). Accompanied by such a double-switching phenomenon, we uncovered that the  $T_{\rm C}$  of this  $({\rm FGT/CS})_3$  superlattice was raised to  $206.3 \pm 1.6$  K (calculated by Arrott-plots, inset of Fig. 2f), reasonably close to the  $T_{\rm C}$  of  $\sim$ 201 K determined by zero-field-cooled and field-cooled (*ZFC-FC*) curves (Fig. 2f). Therefore, a dramatic enhancement of  $T_{\rm C}$  over 60 K is achieved when compared to 140.3 K in 4-layer Fe<sub>3</sub>GeTe<sub>2</sub>. The evolutions of the double-switching AHE and *M-H* curves at various temperatures are provided in Supplementary Figs 5–8. Conjointly, the  $T_{\rm C}$  modulation and double-switching effect are closely related to the interfacial coupling between the ferromagnetic Fe<sub>3</sub>GeTe<sub>2</sub> and antiferromagnetic CrSb.

We further conducted element-specific XMCD at Fe and  $\operatorname{Cr} L_{2,3}$  absorption edges to probe the local electronic character and investigate how the proximity interfacial interaction evolves in (FGT/CS)<sub>3</sub>. In the XMCD measurement, circularly polarized X-ray with 100% left and right polarization was used, denoted as  $\mu^-$  and  $\mu^+$ , respectively. XMCD is defined as the difference of the X-ray absorption spectroscopy (XAS), written as the equation  $XMCD = \mu^- - \mu^+$ . Figure 3a presents a typical pair of XAS and XMCD spectra of Fe  $L_{2,3}$  edge

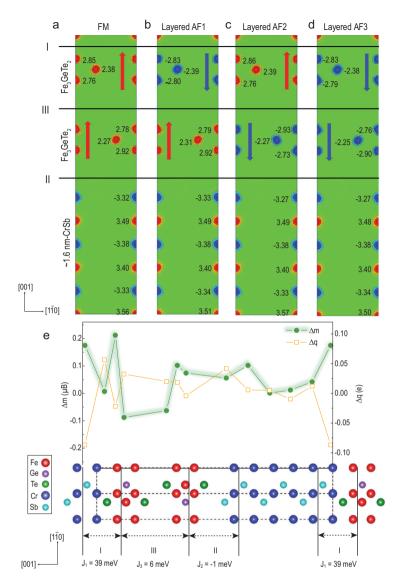
RESEARCH ARTICLE Liu et al. | 749



**Figure 3.** Element-specific magnetic states and  $T_{\rm C}$  modulation in (FGT/CS)<sub>3</sub> superlattice. (a) Typical XAS and XMCD spectra of the Fe  $L_{2,3}$  edge obtained at 3 K. The ferromagnetic state of Fe<sub>3</sub>GeTe<sub>2</sub> can persist up to 200 K. Dashed lines are the integrations of the spectra, which is used to analyze the moments of Fe (see details in Supplementary section 3). (b) Typical XAS and XMCD spectra of the Cr  $L_{2,3}$  edge at 3 K. This ferrimagnetic order results from the interfacial CrSb that is converted from the intrinsic antiferromagnetic state, which induces the double-switching behavior in AHE. (c) Experimental setup of the XMCD measurement. Left ( $\mu^-$ ) and right ( $\mu^+$ ) circular polarized X-ray incident normally onto the sample surface and in parallel to the magnetic field. (d) Temperature-dependent XMCD percentage of the Fe  $L_3$  and Cr  $L_3$  edge. Here, XMCD percentage ( $\beta$ ) is defined in the equation  $\beta = \frac{\mu^- - \mu^+}{\mu^- + \mu^+}$ .  $T_{\rm C} = 208.6 \pm 7.5$  K by fitting the temperature-dependent Fe XMCD percentage using the empirical equation  $(1 - T/T_{\rm C})^{\gamma}$  [46,47], consistent with that obtained from the Arrott-plots (206.3±1.6 K). (e)  $T_{\rm C}$  versus the period n, which increases  $\sim$ 60% from 140.3  $\pm$  2.7 K of the pure 4-layer FGT to 230.9  $\pm$  1.3 K in (FGT/CS)<sub>10</sub> superlattice. Note that the thicknesses of Fe<sub>3</sub>GeTe<sub>2</sub> and CrSb are  $\sim$ 3.2 nm (4-layer) and  $\sim$ 1.6 nm, respectively.

obtained using total electron yield detection mode. The XAS spectra, in good agreement with Fe<sub>3</sub>GeTe<sub>2</sub>. bulks [45] in the spectrum shape and energy positions, confirm that the Fe-magnetism originates from the Fe<sub>3</sub>GeTe<sub>2</sub> region. Consistent with the  $T_C$ determined by the AHE measurements (206.3 K), the XMCD signals can be distinguished at 200 K and vanish at 300 K (Fig. 3a). Significantly, Cr  $L_{2,3}$  spectra give a strong XMCD dichroism at 3 K (Fig. 3b), indicating the newly developed Cr magnetic state at the interface. This Cr ferrimagnetic order can be detected at 50 K and becomes much weaker when approaching 100 K (Fig. 3b). By revisiting the AHE measurements, we note that the two magnetic states from intrinsic Fe<sub>3</sub>GeTe<sub>2</sub> and interfacial CrSb can individually contribute to the resistance jump at each  $H_C$ , and accordingly, the double-switching behavior occurs. Here, XMCD percentage  $(\beta)$ , defined by  $\beta = \frac{\mu^- - \mu^+}{\mu^- + \mu^+}$ , is used to analyze the ferromagnetism. By fitting the temperature-dependent Fe XMCD percentage to the empirical function of  $(1 - T/T_C)^{\gamma}$  [46,47],  $T_{\rm C}$  is calculated to be 208.6  $\pm$  7.5 K (Fig. 3d), which is consistent with the magneto-transport measurements. The same positive trends of Cr and Fe spectra as a function of the magnetic field indicate parallel interfacial ferromagnetic coupling between  $Fe_3GeTe_2$  and CrSb (see details in Supplementary Fig. 10) [47], which agrees with the negative  $H_{EX}$  at minor loop  $\mathbb{Q}$  (Fig. 2d).

Now, we summarize the various  $T_{\rm C}$  for  $(FGT/CS)_n$  superlattices as a function of period n. Here,  $T_{\rm C}$  is extracted by Arrott-plots (Supplementary Figs 11-12). As shown in Fig. 3e, a giant improvement of  $T_{\rm C}$  is observed in the (FGT/CS)<sub>n</sub> superlattice. Once the FGT/CS bilayer is established, denoted as  $(FGT/CS)_1$ ,  $T_C$  can be noticeably raised to 178.7  $\pm$  2.5 K,  $\sim$ 40 K higher than that of the pure 4-layer Fe<sub>3</sub>GeTe<sub>2</sub>.  $T_C$  increases continuously as *n* increases to above 5, above which it saturates at ~230 K. Despite the dimensionality effect on the  $T_{\rm C}$  of pure Fe<sub>3</sub>GeTe<sub>2</sub>, which is given in detail in Fig. 1f, when comparing the  $T_{\mathbb{C}}$  in pure 4-layer FGT with (4-layer FGT/CS)<sub>1</sub>, and  $T_{\rm C}$ in bulk FGT with (4-layer FGT/CS)9 where the thickness of FGT in the superlattices is fixed at 4-layer, we believe that besides the dimensionality effect, the FGT/CS interfacial interactions play a



**Figure 4.** DFT calculations for FGT/CS superlattice. (a–d) Spin density plots in the (110) plane of FGT/CS superlattice in four different magnetic states of FM, Layered AF1, Layered AF2 and Layered AF3, respectively. Red (blue) color stands for the Fe or Cr up (down) spin. The magnetic moments are marked for each atom. (e) Three kinds of interfaces in the FGT/CS superlattice: Fe-Te/Cr-Sb interface named interface I, Fe-Te/Sb-Cr interface named interface II and FGT van der Waals monolayer interface named interface III with the exchange constants for each corresponding interface defined as  $J_1$ ,  $J_2$  and  $J_3$ , respectively. The changes of atomic charge ( $\Delta q$ ) and magnetic moments ( $\Delta m$ ) of the FGT/CS superlattice against the FGT monolayer and CS bulk. Compared to interface II, larger ( $\Delta q$ ,  $\Delta m$ ) and the exchange constant  $J_1 = 39$  meV can be determined at the FM coupled interface I, which result in significant  $T_C$  enhancement in the FGT layer.

more important role in the  $T_{\rm C}$  increase in these superlattices. The mechanism is proposed in the following section.

#### THEORETICAL CALCULATION

To seek the origin of such a  $T_{\rm C}$  enhancement in the FGT/CS superlattices, we performed DFT cal-

**Table 1.** ( $J_1$ ,  $J_2$ ,  $J_3$ ) magnetic exchange model, relative total energy  $\Delta E$  (meV/cell) and total magnetic moments (Tot,  $\mu_B/\text{fu}$ ) of the FGT/CS.

FGT/CS	Energy <sup>a</sup>	$\Delta E \text{ (meV/fu)}$	Tot $(\mu_{\rm B}/{ m fu})$
FM	$-J_1-J_3+J_2$	0	7.89
Layered-AF1	$J_1 + J_3 + J_2$	90	0.30
Layered-AF2	$-J_1+J_3-J_2$	14	0.46
Layered-AF3	$J_1 - J_3 - J_2$	80	-7.16

 $<sup>^{</sup>a}J_{1}=39$  meV,  $J_{2}=-1$  meV,  $J_{3}=6$  meV are derived.

culations within the Generalized Gradient Approximation (GGA) plus U framework. Taking into account the robust FM ground state of Fe<sub>3</sub>GeTe<sub>2</sub> monolayer and the A-AF state of CS (Supplementary section 5), we constructed four different magnetic states (Fig. 4a-d) for the FGT/CS superlattice to address three magnetic couplings at the Fe-Te/Cr-Sb interface (I), at the Fe-Te/Sb-Cr interface (II) and in-between the two FGT van der Waals (vdW) layers (III), corresponding to the exchange constants  $J_1$ ,  $J_2$  and  $J_3$ , respectively (Fig. 4e). We mapped the calculated energy differences (summarized in Table 1) onto a simple  $(J_1, J_2, J_3)$  magnetic exchange model. We found that while the Fe-Te/Cr-Sb interface has a strong FM coupling  $(J_1 =$ 39 meV), the Fe-Te/Sb-Cr interface is very weakly AF coupled  $(J_2 = -1 \text{ meV})$ , and the two FGT vdW layers have moderate FM coupling  $(J_3 = 6 \text{ meV})$ . The very weak J<sub>2</sub> coupling is a result of large Fe—Cr separation by Te-Sb atoms. The strong J<sub>1</sub> exchange is associated with the intact Fe-Te-Cr pathway in which the Cr atom moves closely to Te to remove its otherwise dangling bond. The moderate J<sub>3</sub> value of 6 meV here is comparable to the calculated value of 7.5 meV for the FGT bulk, where the experimental vdW interlayer Te-Te distance of 2.94 Å is smaller than the optimized theoretical value of 3.02 Å. Therefore, we suggest that the FGT/CS superlattice has a strong FM Fe-Te/Cr-Sb interface (I) but a weak AF Fe-Te/Sb-Te interface (II) and moderately FM coupled vdW FGT monolayers (III).

As the Fe-Te/Cr-Sb interface I is strongly FM coupled, it tunes the magnetic behavior of the interfacial FGT monolayer: when this FGT monolayer is changed from the FM ground state to the tri-layered AF state (i.e. up-up-up spins to up-down-up spins as shown in Supplementary Fig. 14c–d, respectively), the total energy rises drastically, from 595 meV/fu for a bare FGT monolayer to 820 meV/fu (per fu of FGT). In contrast, the corresponding energy difference is reduced to 424 meV/fu for the FGT monolayer lying at the Fe-Te/Sb-Cr interface II, which is weakly AF coupled. Obviously, the significant enhancement of FM coupling in the FGT vdW layer at the Fe-Te/Cr-Sb interface I dominates

RESEARCH ARTICLE Liu et al. | 751

over the reduction at the Fe-Te/Sb-Cr interface II (caused by negative effects from the tensile strain (see Supplementary section 5) and the weak AF interfacial coupling here). Moreover, it is believed that for the interior FGT vdW layers in the FGT/CS superlattice, their intralayer and interlayer FM couplings should be very similar to their bulk cases.

#### CONCLUSION

In Fig. 4e, we plot the changes of atomic charge  $(\Delta q)$  and magnetic moments  $(\Delta m)$  of a representative 2-layer FGT/1.6nm-CS superlattice against the FGT monolayer and the CS bulk. It can be observed that the Fe-Te/Cr-Sb interface I has much larger charge/moment changes than those at the Fe-Te/Sb-Cr interface II. More specifically, for the 'more important' Fe-Te/Cr-Sb interface I, the Cr atoms donate some electrons to the neighboring FGT vdW layer, and therefore the Cr atoms and FGT monolayer both have increased magnetic moments. Together, these contribute to the above significant enhancement of FM coupling in the FGT vdW layer at the strongly FM coupled Fe-Te/Cr-Sb interface I, and eventually to the remarkable  $T_{\rm C}$  enhancement in FGT films of the FGT/CS superlattice. Moreover, because of this spin-polarized charge transfer, the interlayer AF coupled Cr layers in CrSb become ferrimagnetic and thus have a net magnetic moment, which accounts for the above XMCD observations (Fig. 3c).

Inspired by the  $T_C$  tunability in  $Fe_{3+x}GeTe_2$ via chemical doping [9,26], we created a similar superlattice using Fe-rich Fe3+xGeTe2 with CrSb to achieve even higher  $T_{\rm C}$ . From the AHE measurements, the hysteresis can be distinguished up to 280 K (Fig. 5a), based on which  $T_{\rm C}$  in  $({\rm Fe_{3+x}GeTe_2/CrSb})_3$  is calculated to be 286.7  $\pm$  5.4 K (Arrott-plots, Supplementary Fig. 13), in good agreement with the  $T_{\rm C}$  of  $\sim$ 280 K determined from ZFC-FC (Fig. 5b). Considering the evolutions of the  $T_C$  in the  $(FGT/CS)_n$  superlattice, in these (Fe<sub>3+x</sub>GeTe<sub>2</sub>/CrSb)<sub>n</sub> samples, we plotted the  $T_{\mathbb{C}}$  as a function of n from n = 0 to n = 3 in Fig. 5c. Similar to the period-dependent  $T_{\rm C}$  in the (FGT/CS)<sub>n</sub> superlattice, with the period increasing,  $T_C$  shows a rising trend up to n = 3, with  $\sim$ 70 K increase to 286.7 K  $\pm$  5.4 K (n = 3). To this point, we achieved a  $T_{\rm C}$  of  $\sim$ 286.7 K in 4-layer 2D  $Fe_{3+x}GeTe_2$  films via the proximity effect.

In summary, we have developed atomically thin 2D ferromagnetic  $Fe_3GeTe_2$  films on a large scale even down to bilayer by precisely controlling epitaxial growth rate. Combined with the AF CrSb, a parallel ferromagnetic interface interaction between  $Fe_3GeTe_2$  and CrSb induces an enormous  $T_C$  en-

hancement up to 286.7 K in the superlattice structure from a low- $T_{\rm C}$  of 140.3 K in the pure 4-layer Fe<sub>3</sub>GeTe<sub>2</sub>. Interestingly, the double-switching behavior is observed for the first time in this system as a result of a proximity effect between FGT and Cr layers. In support of these abundant experiments, our DFT calculations found that the interfacial Cr layers retained their interlayer AF coupling but had a net FM magnetic moment, and that doping the spin-polarized electrons via the interfacial Cr layer gives rise to the  $T_{\rm C}$  enhancement of the Fe<sub>3</sub>GeTe<sub>2</sub> films. Our approach of feasible modulation of  $T_{\rm C}$  enabled by the FM/AF proximity effect, together with the capability of wafer-scale growth, provides a realistic platform for spintronic devices based on 2D FMs.

#### **METHODS**

#### Thin-film synthesis

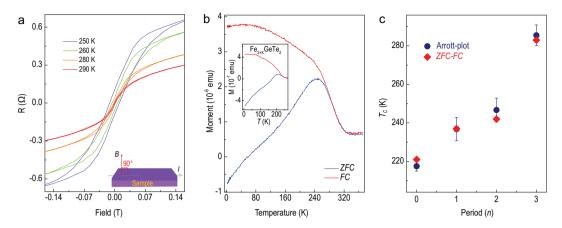
Thin films were grown on mica and (0001) sapphire in a Perkin Elmer 430 MBE system with a base vacuum of  $2.5 \times 10^{-9}$  Torr. The growth substrate temperature for Fe<sub>3</sub>GeTe<sub>2</sub> was  $\sim 310^{\circ}$ C, with the source temperatures of Fe (99.99%), Ge (99.999%) and Te (99.999%) at  $1165^{\circ}$ C,  $1020^{\circ}$ C and  $285^{\circ}$ C, respectively. They were co-evaporated from standard Knudsen cells. CrSb films were grown at the substrate temperature of  $280^{\circ}$ C, with Cr (99.99%) and Sb (99.999%) cell temperatures of  $1180^{\circ}$ C and  $400^{\circ}$ C, respectively. The flux of each element was calibrated by the crystal monitor. The MBE system was equipped with an *in situ* RHEED.

#### Thin-film characterizations

Structural characterizations of Fe<sub>3</sub>GeTe<sub>2</sub> and CrSb samples were carried out by X-ray diffraction (Bruker D8 Discover, Bruker Inc., Billerica, MA, USA) and TEM (FEI Tecnai F20) equipped with EDS. Sample composition and doping concentration were determined by EDS. Cross-section TEM samples were prepared by Focused ion beam (FEI Scios DualBeam).

# Electrical and magnetization characterizations

Magneto-transport measurements were performed with the Physical Properties Measurement System by Quantum Design. The magneto-transport devices were confined to the Hall-bar geometry. Experimental data were collected using lock-in amplifiers (Stanford Research 830, Stanford Research Systems, Sunnyvale, CA, USA). The magnetization measurements were taken using



**Figure 5.**  $T_{\rm C}$  enhancement in the (Fe<sub>3+x</sub>GeTe<sub>2</sub>/CrSb) superlattice. (a) Temperature-dependent AHE in (Fe<sub>3+x</sub>GeTe<sub>2</sub>/CrSb)<sub>3</sub>. Up to 280 K, hysteresis can still be observed. The inset is the perpendicular geometry for the measurement. (b) *ZFC-FC* curves for (Fe<sub>3+x</sub>GeTe<sub>2</sub>/CrSb)<sub>3</sub>.  $T_{\rm C}$  can be roughly determined to be  $\sim$ 280 K, complying with that of 286.7  $\pm$  5.4 K calculated by the Arrott-plots (Supplementary Fig. 13). The inset is the *ZFC-FC* curve for the 4-layer Fe<sub>3+x</sub>GeTe<sub>2</sub> with  $T_{\rm C}$  at  $\sim$ 220 K. (c) Period-dependent Curie temperature. As the period increases,  $T_{\rm C}$  can be raised from 217.5  $\pm$  2.6 K (n = 0, the pure Fe<sub>3+x</sub>GeTe<sub>2</sub>) to 286.7 $\pm$ 5.4 K (n = 3, the superlattice). The definition of period n = 1 is a bilayer structure of Fe<sub>3+x</sub>GeTe<sub>2</sub> and CrSb, the same as that depicted in Fig. 3d inset. The thickness of Fe<sub>3+x</sub>GeTe<sub>2</sub> and CrSb is  $\sim$ 3.2 nm and  $\sim$ 1.6 nm, respectively.

DC-Superconducting-Quantum-Interface-Devices (SQUID) by Quantum Design.

# X-ray magnetic circular dichroism measurement

XMCD measurements were performed on Beamline I10 at the Diamond Light Source, UK (100% polarized X-rays), and beamline 6.3.1 at the Advanced Light Source, Berkeley, CA (65% polarized X-rays). During the data acquisition, the polarization of X-ray is switched with a fixed magnetic field at every energy point (Beamline I10), and the field direction is switched without changing the polarization at every energy point (Beamline 6.3.1). Such polarization switching at each energy point ensures identical sample conditions for the measurements.

### **Density functional theory calculations**

We performed DFT calculations using the Vienna Ab initio Simulation Package with a plane wave basis set [48]. The ionic potentials including the effect of core electrons are described by the projector augmented wave method, and the GGA was used as the exchange-correlation functional [49]. To better describe the interactions between CrSb and  $Fe_3GeTe_2$  in the superlattices, the vdW corrections were considered within Grimme's approach (DFT-D2) [50]. The plane waves with the kinetic energy up to 400 eV were employed to expand the electronic wave functions. Integration over the first Brillouin zone was carried out using the

Monkhorst-Pack grid of  $7 \times 7 \times 5$  k-point mesh. The structural relaxations were performed till the Hellmann-Feynman force on each atom was smaller than 0.01 eV/Å. Experimental lattice constants were adopted [34,36]. A 24-atom superlattice consisting of  $1 \times 1 \times 1$  unit cell of Fe<sub>3</sub>GeTe<sub>2</sub> (12 atoms) and  $1 \times 1 \times 3$  lattice of CrSb (12 atoms) was used to study the interfacial interactions. The Coulomb and exchange parameters U = 3.5 (3.0) eV and J = 0.9 (0.9) eV were chosen for Fe (Cr) 3d electrons [51,52]. Bader charge analysis was used to identify the interfacial Cr-Fe charge transfer [53].

#### **SUPPLEMENTARY DATA**

Supplementary data are available at NSR online.

#### **ACKNOWLEDGEMENTS**

J.Z. acknowledges the Australian Research Council. Diamond Light Source is acknowledged to 110 under Proposal SI20748. This research used resources of the Advanced Light Source, which is a DOE Office of Science User Facility under contract No. DEAC02-05CH11231. Part of the sample fabrication was performed at Fudan Nano-fabrication Laboratory.

#### **FUNDING**

This work was supported by the National Natural Science Foundation of China (61674040, 11874116, 11934005, 61322407, 11474059, 11674064, 61427812 and 11774160), the National Key Research and Development Program of China (2018YFA0305601, 2017YFA0303302, 2018YFA0305601 and

2016YFA0300700), the Science and Technology Commission of Shanghai (19511120500), the National Basic Research Program of China (2014CB921101 and 2016YFA0300803), the UK EPSRC (EP/S010246/1), the Royal Society (IEC/NSFC/181680), Leverhulme Trust (LTSRF1819/15/12), Singapore Ministry of Education Tier 2 grants (MOE2016-T2-2-110) and Pharos R-144-000-359-305. E.Z. acknowledges support from China Postdoctoral Innovative Talents Support Program (BX20190085) and China Postdoctoral Science Foundation (2019M661331).

Conflict of interest statement. None declared.

#### **REFERENCES**

- Novoselov KS, Geim AK and Morozov SV et al. Two-dimensional gas of massless Dirac fermions in graphene. Nature 2005; 438: 197–200.
- Zhang Y, Tan Y-W and Stormer HL et al. Experimental observation of the quantum Hall effect and Berry's phase in graphene. Nature 2005; 438: 201–4.
- Radisavljevic B, Radenovic A and Brivio J et al. Single-layer MoS<sub>2</sub> transistors. Nat Nanotechnol 2011; 6: 147–50.
- Zafar A, Zafar Z and Zhao W et al. Sulfur-mastery: precise synthesis of 2D transition metal dichalcogenides. Adv Funct Mater 2019; 29: 1809261.
- Efetov DK, Wang L and Handschin C et al. Specular interband Andreev reflections at van der Waals interfaces between graphene and NbSe<sub>2</sub>. Nat Phys 2016; 12: 328–32.
- Zhang E, Zhi J and Zou Y-C et al. Signature of quantum Griffiths singularity state in a layered quasi-one-dimensional superconductor. Nat Commun 2018; 9: 4656.
- Gong C, Li L and Li Z et al. Discovery of intrinsic ferromagnetism in two-dimensional van der Waals crystals. Nature 2017; 546: 265–9
- 8. Huang B, Clark G and Navarro-Moratalla E *et al.* Layer-dependent ferromagnetism in a van der Waals crystal down to the monolayer limit. *Nature* 2017; **546**: 270–3.
- 9. Liu S, Yuan X and Zou Y *et al.* Wafer-scale two-dimensional ferromagnetic Fe<sub>3</sub>GeTe<sub>2</sub> thin films grown by molecular beam epitaxy. *Npj 2D Mater Appl* 2017; **1**: 30.
- Fei Z, Huang B and Malinowski P et al. Two-dimensional itinerant ferromagnetism in atomically thin Fe<sub>3</sub>GeTe<sub>2</sub>. Nat Mater 2018; 17: 778–82.
- Deng Y, Yu Y and Song Y et al. Gate-tunable room-temperature ferromagnetism in two-dimensional Fe<sub>3</sub>GeTe<sub>2</sub>. Nature 2018; 563: 94–9.
- 12. Tan C, Lee J and Jung S-G *et al.* Hard magnetic properties in nanoflake van der Waals Fe<sub>3</sub>GeTe<sub>2</sub>. *Nat Commun* 2018; **9**: 1554.
- Wang Z, Gutiérrez-Lezama I and Ubrig N et al. Very large tunneling magnetoresistance in layered magnetic semiconductor Crl<sub>3</sub>. Nat Commun 2018; 9: 2516.
- Klein DR, MacNeill D and Lado JL et al. Probing magnetism in 2D van der Waals crystalline insulators via electron tunneling. Science 2018; 360: 1218–22.

- Song T, Cai X and Tu MW-Y et al. Giant tunneling magnetoresistance in spin-filter van der Waals heterostructures. Science 2018: 340: 1214–8.
- Ghazaryan D, Greenaway MT and Wang Z et al. Magnonassisted tunnelling in van der Waals heterostructures based on CrBr<sub>3</sub>. Nat Electron 2018; 1: 344–9.
- Wang Z, Sapkota D and Taniguchi T et al. Tunneling spin valves based on Fe<sub>3</sub>GeTe<sub>2</sub>/hBN/Fe<sub>3</sub>GeTe<sub>2</sub> van der Waals heterostructures. Nano Lett 2018; 18: 4303–8.
- Dzyaloshinsky I. A thermodynamic theory of 'weak' ferromagnetism of antiferromagnetics. J Phys Chem Solids 1958; 4: 241–55
- Moriya T. Anisotropic superexchange interaction and weak ferromagnetism. *Phys Rev* 1960; **120**: 91–8.
- Park T-E, Peng L and Zhang X et al. Observation of magnetic skyrmion crystals in a van der Waals ferromagnet Fe<sub>3</sub>GeTe<sub>2</sub>. arXiv: 190701425.
- Wu Y, Zhang S and Yin G et al. Néel-type skyrmion in WTe<sub>2</sub>/Fe<sub>3</sub>GeTe<sub>2</sub> van der Waals heterostructure. arXiv: 190711349.
- 22. Mermin ND and Wagner H. Absence of ferromagnetism or antiferromagnetism in one- or two-dimensional isotropic Heisenberg models. *Phys Rev Lett* 1966; **17**: 1133–6.
- 23. Huang B, Clark G and Klein DR *et al.* Electrical control of 2D magnetism in bilayer Crl<sub>3</sub>. *Nat Nanotechnol* 2018; **13**: 544–8.
- 24. Jiang S, Li L and Wang Z *et al.* Controlling magnetism in 2D Crl<sub>3</sub> by electrostatic doping. *Nat Nanotechnol* 2018; **13**: 549–53.
- Jiang S, Shan J and Mak KF. Electric-field switching of twodimensional van der Waals magnets. *Nat Mater* 2018; 17: 406– 10
- 26. May AF, Calder S and Cantoni C *et al.* Magnetic structure and phase stability of the van der Waals bonded ferromagnet Fe<sub>3-x</sub>GeTe<sub>2</sub>. *Phys Rev B* 2016; **93**: 014411.
- Nogués J and Schuller IK. Exchange bias. J Magn Magn Mater 1999; 192: 203–32.
- 28. Žutić I, Matos-Abiague A and Scharf B *et al.* Proximitized materials. *Mater Today* 2019; **22**: 85–107.
- 29. Katmis F, Lauter V and Nogueira FS *et al.* A high-temperature ferromagnetic topological insulating phase by proximity coupling. *Nature* 2016; **533**: 513–6.
- Qiao Z, Ren W and Chen H et al. Quantum anomalous Hall effect in graphene proximity coupled to an antiferromagnetic insulator. Phys Rev Lett 2014; 112: 116404.
- Lang M, Montazeri M and Onbasli MC et al. Proximity induced high-temperature magnetic order in topological insulator - ferrimagnetic insulator heterostructure. Nano Lett 2014; 14: 3459– 65.
- 32. Wei P, Katmis F and Assaf BA *et al.* Exchange-coupling-induced symmetry breaking in topological insulators. *Phys Rev Lett* 2013; **110**: 186807.
- He QL, Kou X and Grutter AJ et al. Tailoring exchange couplings in magnetic topological-insulator/antiferromagnet heterostructures. Nat Mater 2017: 16: 94–100.

 Deiseroth H-J, Aleksandrov K and Reiner C et al. Fe<sub>3</sub>GeTe<sub>2</sub> and Ni<sub>3</sub>GeTe<sub>2</sub>—
two new layered transition-metal compounds: crystal structures, HRTEM investigations, and magnetic and electrical properties. Eur J Inorg Chem 2006; 2006: 1561–7.

- Abe S, Kaneko T and Ohashi M et al. Magnetic properties of CrSb. J Phys Soc Jpn 1984; 53: 2703–9.
- Willis BTM. Crystal structure and antiferromagnetism of CrSb. Acta Cryst 1953;
   425–6
- Zhang R and Willis RF. Thickness-dependent curie temperatures of ultrathin magnetic films: effect of the range of spin-spin interactions. *Phys Rev Lett* 2001; 86: 2665–8.
- Fisher ME and Barber MN. Scaling theory for finite-size effects in the critical region. Phys Rev Lett 1972; 28: 1516–9.
- Ritchie DS and Fisher ME. Finite-size and surface effects in Heisenberg films. Phys Rev B 1973; 7: 480–94.
- Chen K, Ferrenberg AM and Landau DP. Static critical behavior of threedimensional classical Heisenberg models: a high-resolution Monte Carlo study. *Phys Rev B* 1993; 48: 3249–56.
- Ferrenberg AM and Landau DP. Critical behavior of the three-dimensional Ising model: a high-resolution Monte Carlo study. Phys Rev B 1991; 44: 5081–91.
- Kirk TL, Hellwig O and Fullerton EE. Coercivity mechanisms in positive exchange-biased Co films and Co/Pt multilayers. Phys Rev B 2002; 65: 224426.
- 43. Ziese M, Bern F and Vrejoiu I. Exchange bias in manganite/SrRuO<sub>3</sub> superlattices. *J Appl Phys* 2013; **113**: 063911.

- 44. Liu ZY and Adenwalla S. Oscillatory interlayer exchange coupling and its temperature dependence in [Pt/Co]<sub>3</sub>/NiO/[Co/Pt]<sub>3</sub> multilayers with perpendicular anisotropy. *Phys Rev Lett* 2003; **91**: 037207.
- Zhu J-X, Janoschek M and Chaves DS et al. Electronic correlation and magnetism in the ferromagnetic metal Fe<sub>3</sub>GeTe<sub>2</sub>. Phys Rev B 2016; 93: 144404
- 46. Ormaza M, Fernández L and Ilyn M *et al.* High temperature ferromagnetism in a GdAg<sub>2</sub> monolayer. *Nano Lett* 2016; **16**: 4230–5.
- 47. Ye M, Li W and Zhu S *et al.* Carrier-mediated ferromagnetism in the magnetic topological insulator Cr-doped (Sb,Bi)<sub>2</sub>Te<sub>3</sub>. *Nat Commun* 2015; **6**: 8913.
- 48. Kresse G and Furthmüller J. Efficient iterative schemes for ab initio total-energy calculations using a plane-wave basis set. *Phys Rev B* 1996; **54**: 11169–86.
- Perdew JP, Burke K and Ernzerhof M. Generalized gradient approximation made simple. Phys Rev Lett 1996; 77: 3865–8.
- Grimme S. Semiempirical GGA-type density functional constructed with a longrange dispersion correction. J Comput Chem 2006; 27: 1787–99.
- Zhuang HL, Kent PRC and Hennig RG. Strong anisotropy and magnetostriction in the two-dimensional Stoner ferromagnet Fe<sub>3</sub>GeTe<sub>2</sub>. Phys Rev B 2016; 93: 134407
- Huang C, Feng J and Wu F et al. Toward intrinsic room-temperature ferromagnetism in two-dimensional semiconductors. J Am Chem Soc 2018; 140: 11519–25.
- Tang W, Sanville E and Henkelman G. A grid-based Bader analysis algorithm without lattice bias. J Phys Condens Matter 2009; 21: 084204.